

High Frequency High Gain DUAL NPN Power BJT

> Features

VCB	VCE	VEB	IC
60V	50V	7V	150mA

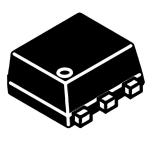
Description

This device is designed for general-purpose high-voltage amplifiers and gas discharge display drivers. It is Ideal for medium power amplification and switching.

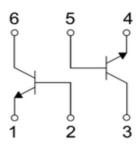
Applications

- General-purpose high-voltage amplifiers
- Gas discharge display drivers
- Medium power amplification and switching

Pin configuration



SOT-563



Circuit Diagram

Ordering Information

Device	Package	Shipping	
SSCNEMX1GSF	SOT-563	3000/Reel	



Marking(Top View)



ightarrow Absolute Maximum Ratings(T_A=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	60	V
Collector- Emitter Voltage	V _{CEO}	50	V
Emitter-Base Voltage	V _{EBO}	7	V
Collector Current-Continuous	Ic	150	mA
Collector Power Dissipation	Pc	150	mW
Junction Temperature	TJ	-55 to 150	$^{\circ}$
Storage Temperature	T _{STG}	-55 to 150	$^{\circ}$

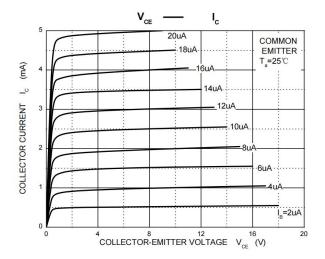
➤ Electrical Characteristics (T_A=25°C unless otherwise noted)

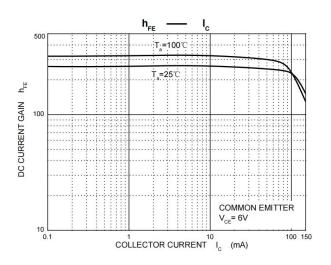
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Collector-Base Breakdown Voltage	BV _{CBO}	I _C = 50uA, I _E =0	60			V
Collector-emitter Breakdown Voltage	BV _{CEO}	I _C =1mA, I _B =0	50			V
Emitter -Base Breakdown Voltage	BV _{EBO}	I _E =50uA, I _C =0	7			V
Collector Cutoff Current	I _{CBO}	V _{CB} =60V, I _E =0			0.1	μA
Emitter Cutoff Current	I _{EBO}	V _{EB} =7V, I _C =0			0.1	μA
DC Current Gain	h _{FE}	V _{CE} =6V, I _C =1mA	120		560	
Collector-Emitter Saturation Voltage	V _{CE} (sat)	I _C =50mA, I _B =5mA			0.4	V
Transition frequency	f⊤	V _{CE} =12V, I _C =2mA		180		MHz
Transition frequency		f=100MHz		160		
Collector output capacitance	Cob	V _{CB} =12V, I _E =0		2.0	3.5	pF
Collector output capacitance		f=1MHz		2.0		

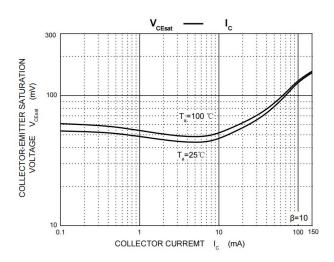


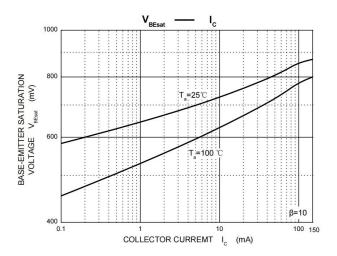


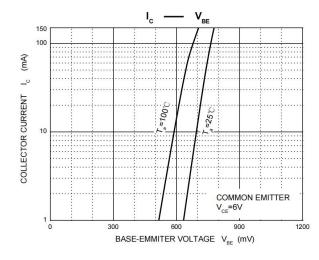
> Typical Performance Characteristics (T_A=25℃ unless otherwise noted)

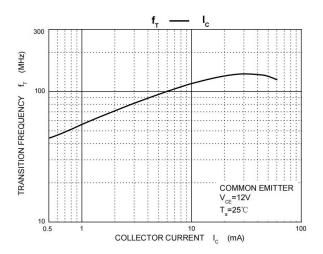




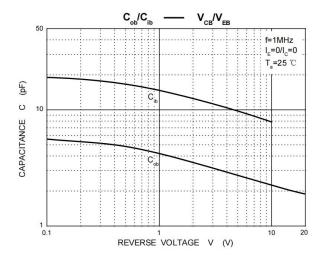


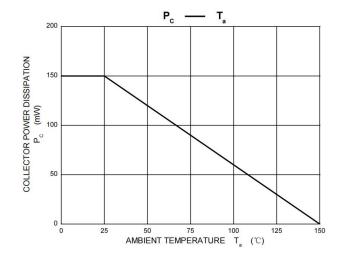








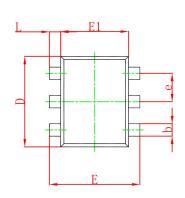


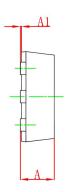


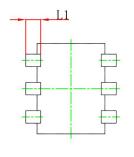


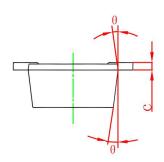
> Package Information





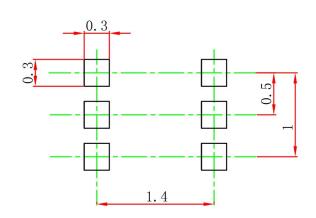






Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
A	0. 525	0.600	0.021	0.024	
A1	0.000	0.050	0.000	0.002	
е	0. 450	0. 550	0.018	0.022	
С	0.090	0. 160	0.004	0.006	
D	1. 500	1. 700	0.059	0.067	
b	0. 170	0. 270	0.007	0.011	
E1	1. 100	1. 300	0.043	0.051	
Е	1.500	1.700	0.059	0.067	
L	0. 100	0.300	0.004	0.012	
L1	0. 200	0.400	0.008	0.016	
θ	7 °REF.			7 ⁰ REF.	

> SOT-563 Suggested Pad Layout



Note:

- 1. Controlling dimension:in millimeters.
- 2.General tolerance:±0.05mm.
- 3. The pad layout is for reference purposes only.

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